

# NE592

## Video Amplifier

The NE592 is a monolithic, two-stage, differential output, wideband video amplifier. It offers fixed gains of 100 and 400 without external components and adjustable gains from 400 to 0 with one external resistor. The input stage has been designed so that with the addition of a few external reactive elements between the gain select terminals, the circuit can function as a high-pass, low-pass, or band-pass filter. This feature makes the circuit ideal for use as a video or pulse amplifier in communications, magnetic memories, display, video recorder systems, and floppy disk head amplifiers. Now available in an 8-pin version with fixed gain of 400 without external components and adjustable gain from 400 to 0 with one external resistor.

### Features

- 120 MHz Unity Gain Bandwidth
- Adjustable Gains from 0 to 400
- Adjustable Pass Band
- No Frequency Compensation Required
- Wave Shaping with Minimal External Components
- MIL-STD Processing Available

### Applications

- Floppy Disk Head Amplifier
- Video Amplifier
- Pulse Amplifier in Communications
- Magnetic Memory
- Video Recorder Systems



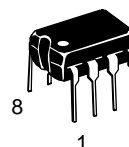
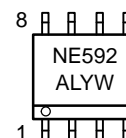
**ON Semiconductor®**

<http://onsemi.com>

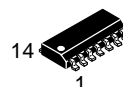
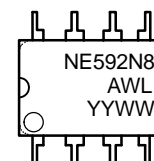
### MARKING DIAGRAMS



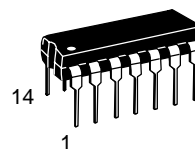
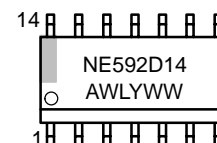
**SOIC-8**  
**D SUFFIX**  
**CASE 751**



**PDIP-8**  
**N SUFFIX**  
**CASE 626**



**SOIC-14**  
**D SUFFIX**  
**CASE 751A**



**PDIP-14**  
**N SUFFIX**  
**CASE 646**



A = Assembly Location  
WL, L = Wafer Lot  
YY, Y = Year  
WW, W = Work Week

### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

# NE592

## PIN CONNECTIONS

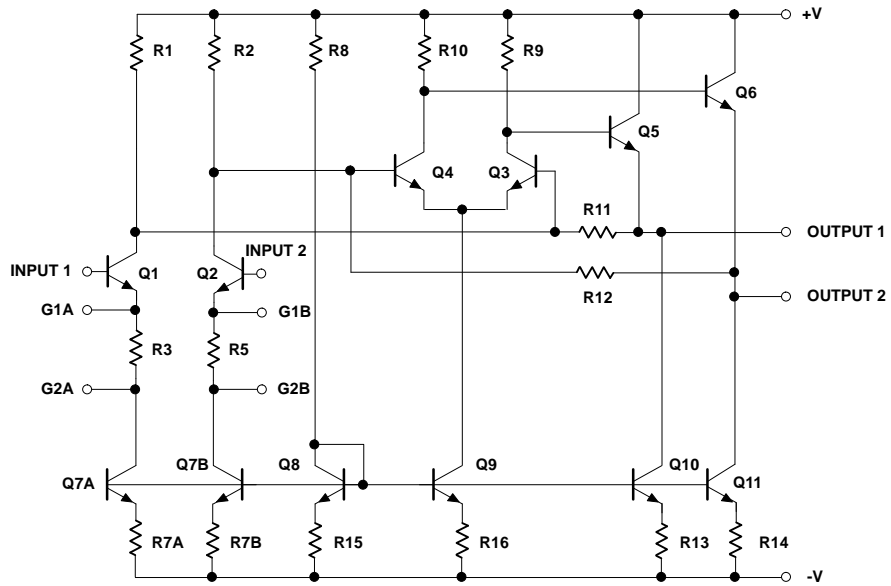
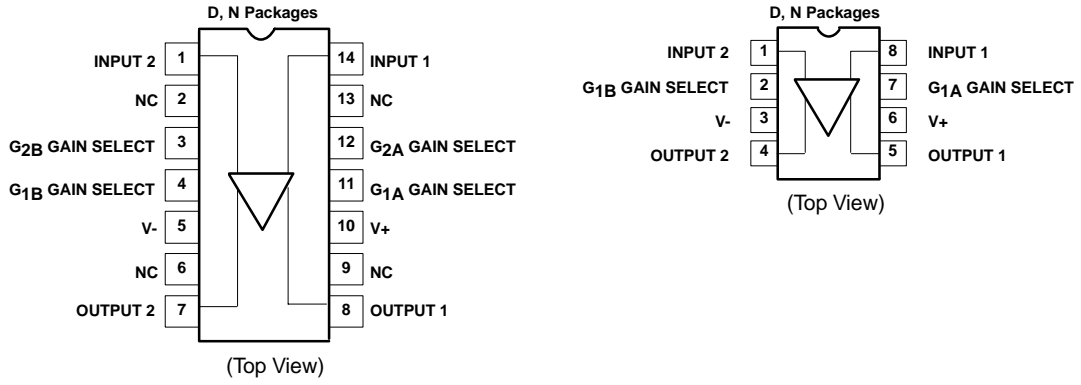


Figure 1. Block Diagram

# NE592

## MAXIMUM RATINGS (T<sub>A</sub> = +25°C, unless otherwise noted.)

Rating	Symbol	Value	Unit
Supply Voltage	V <sub>CC</sub>	± 8.0	V
Differential Input Voltage	V <sub>IN</sub>	± 5.0	V
Common-Mode Input Voltage	V <sub>CM</sub>	± 6.0	V
Output Current	I <sub>OUT</sub>	10	mA
Operating Ambient Temperature Range	T <sub>A</sub>	0 to +70	°C
Operating Junction Temperature	T <sub>J</sub>	150	°C
Storage Temperature Range	T <sub>STG</sub>	-65 to +150	°C
Maximum Power Dissipation, T <sub>A</sub> = 25°C (Still Air) (Note 1) D-14 Package D-8 Package N-14 Package N-8 Package	P <sub>D MAX</sub>	0.98 0.79 1.44 1.17	W
Thermal Resistance, Junction-to-Ambient D-14 Package D-8 Package N-14 Package N-8 Package	R <sub>θJA</sub>	145 182 100 130	°C/W

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

- Derate above 25°C at the following rates:  
D-14 package at 6.9 mW/°C  
D-8 package at 5.5 mW/°C  
N-14 package at 10 mW/°C  
N-8 package at 7.7 mW/°C.

# NE592

**DC ELECTRICAL CHARACTERISTICS** ( $V_{SS} = \pm 6.0\text{ V}$ ,  $V_{CM} = 0$ , typicals at  $T_A = +25^\circ\text{C}$ , min and max at  $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ , unless otherwise noted. Recommended operating supply voltages  $V_S = \pm 6.0\text{ V}$ .)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Differential Voltage Gain Gain 1 (Note 2) Gain 2 (Notes 3 and 5)	$A_{VOL}$	$R_L = 2.0\text{ k}\Omega$ , $V_{OUT} = 3.0\text{ V}_{P-P}$	250 80	400 100	600 120	V/V
Input Resistance Gain 1 (Note 2) Gain 2 (Notes 3 and 5)	$R_{IN}$	– $T_A = 25^\circ\text{C}$ $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	– 10 8.0	4.0 30 –	– – –	k $\Omega$
Input Capacitance	$C_{IN}$	Gain 2 (Note 5)	–	2.0	–	pF
Input Offset Current	$I_{OS}$	$T_A = 25^\circ\text{C}$ $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	– –	0.4 –	5.0 6.0	$\mu\text{A}$
Input Bias Current	$I_{BIAS}$	$T_A = 25^\circ\text{C}$ $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	– –	9.0 –	30 40	$\mu\text{A}$
Input Noise Voltage	$V_{NOISE}$	BW 1.0 kHz to 10 MHz	–	12	–	$\mu\text{V}_{RMS}$
Input Voltage Range	$V_{IN}$	–	$\pm 1.0$	–	–	V
Common-Mode Rejection Ratio Gain 2 (Note 5)	CMRR	$V_{CM} \pm 1.0\text{ V}$ , $f < 100\text{ kHz}$ , $T_A = 25^\circ\text{C}$ $V_{CM} \pm 1.0\text{ V}$ , $f < 100\text{ kHz}$ , $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$ $V_{CM} \pm 1.0\text{ V}$ , $f < 5.0\text{ MHz}$	60 50 –	86 – 60	– – –	dB
Supply Voltage Rejection Ratio Gain 2 (Note 5)	PSRR	$\Delta V_S = \pm 0.5\text{ V}$	50	70	–	dB
Output Offset Voltage Gain 1 Gain 2 (Note 5) Gain 3 (Note 4) Gain 3 (Note 4)	$V_{OS}$	$R_L = \infty$ $R_L = \infty$ $R_L = \infty$ , $T_A = 25^\circ\text{C}$ $R_L = \infty$ , $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	– – – –	– – 0.35 –	1.5 1.5 0.75 1.0	V
Output Common-Mode Voltage	$V_{CM}$	$R_L = \infty$ , $T_A = 25^\circ\text{C}$	2.4	2.9	3.4	V
Output Voltage Swing Differential	$V_{OUT}$	$R_L = 2.0\text{ k}\Omega$ , $T_A = 25^\circ\text{C}$ $R_L = 2.0\text{ k}\Omega$ , $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	3.0 2.8	4.0 –	– –	V
Output Resistance	$R_{OUT}$	–	–	20	–	$\Omega$
Power Supply Current	$I_{CC}$	$R_L = \infty$ , $T_A = 25^\circ\text{C}$ $R_L = \infty$ , $0^\circ\text{C} \leq T_A \leq 70^\circ\text{C}$	– –	18 –	24 27	mA

**AC ELECTRICAL CHARACTERISTICS** ( $T_A = +25^\circ\text{C}$ ,  $V_{SS} = \pm 6.0\text{ V}$ ,  $V_{CM} = 0$ , unless otherwise noted. Recommended operating supply voltages  $V_S = \pm 6.0\text{ V}$ .)

Characteristic	Symbol	Test Conditions	Min	Typ	Max	Unit
Bandwidth Gain 1 (Note 2) Gain 2 (Notes 3 and 5)	BW	–	– –	40 90	– –	MHz
Rise Time Gain 1 (Note 2) Gain 2 (Notes 3 and 5)	$t_R$	$V_{OUT} = 1.0\text{ V}_{P-P}$	– –	10.5 4.5	12 –	ns
Propagation Delay Gain 1 (Note 2) Gain 2 (Notes 3 and 5)	$t_{PD}$	$V_{OUT} = 1.0\text{ V}_{P-P}$	– –	7.5 6.0	10 –	ns

2. Gain select Pins  $G_{1A}$  and  $G_{1B}$  connected together.
3. Gain select Pins  $G_{2A}$  and  $G_{2B}$  connected together.
4. All gain select pins open.
5. Applies to 14-pin version only.

TYPICAL PERFORMANCE CHARACTERISTICS

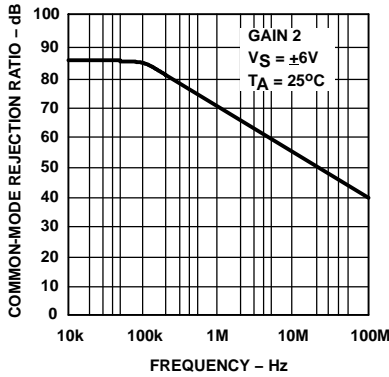


Figure 2. Common-Mode Rejection Ratio as a Function of Frequency

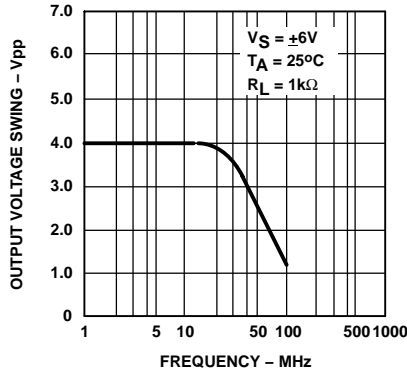


Figure 3. Output Voltage Swing as a Function of Frequency

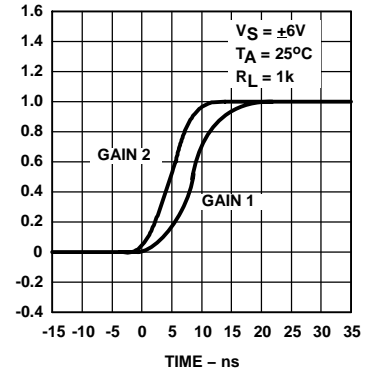


Figure 4. Pulse Response

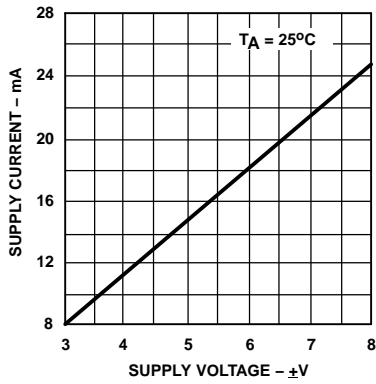


Figure 5. Supply Current as a Function of Temperature

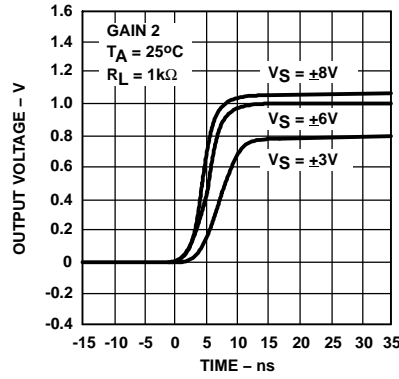


Figure 6. Pulse Response as a Function of Supply Voltage

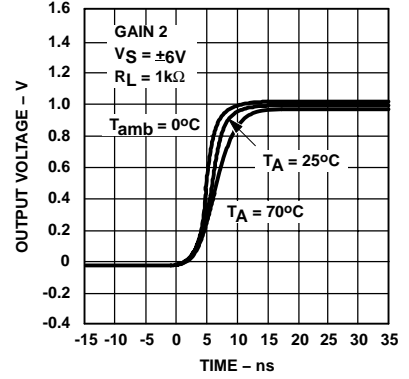


Figure 7. Pulse Response as a Function of Temperature

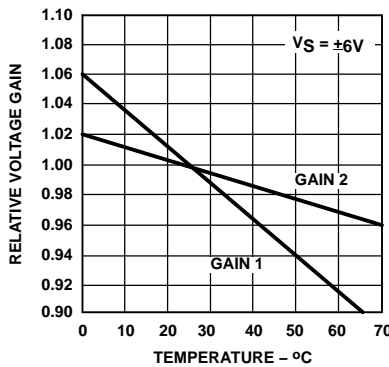


Figure 8. Voltage Gain as a Function of Temperature

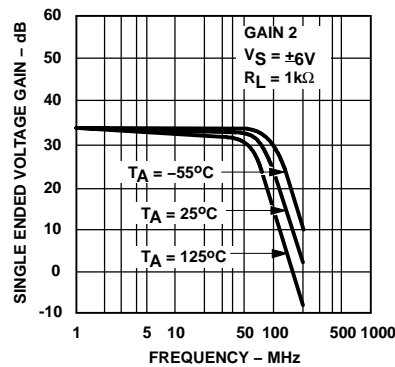


Figure 9. Gain vs. Frequency as a Function of Temperature

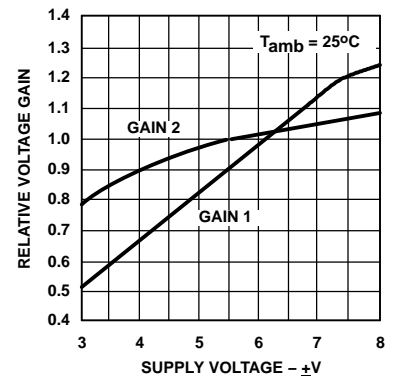


Figure 10. Voltage Gain as a Function of Supply Voltage

TYPICAL PERFORMANCE CHARACTERISTICS

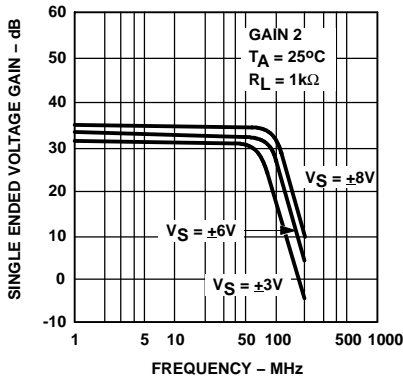


Figure 11. Gain vs. Frequency as a Function of Supply Voltage

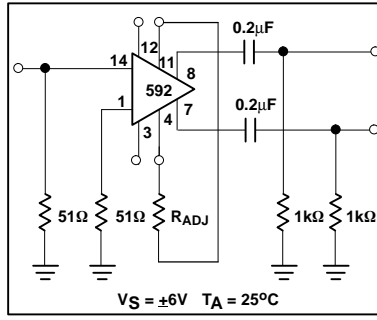


Figure 12. Voltage Gain Adjust Circuit

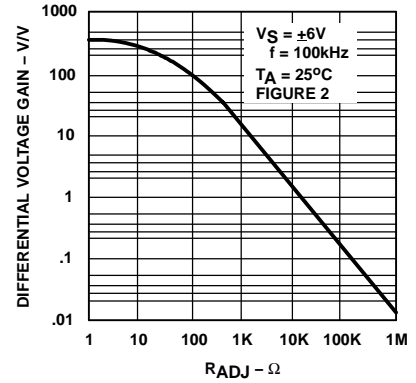


Figure 13. Voltage Gain as a Function of RADJ (Figure 2)

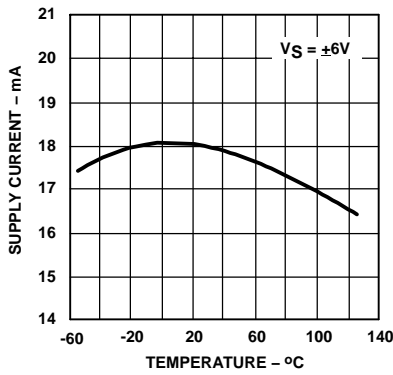


Figure 14. Supply Current as a Function of Temperature

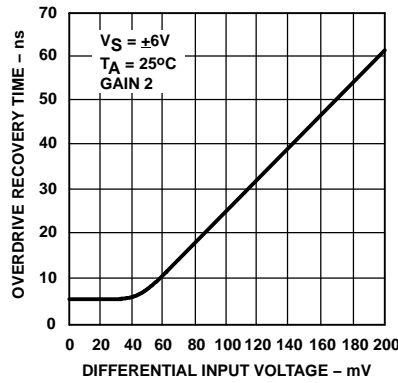


Figure 15. Differential Overdrive Recovery Time

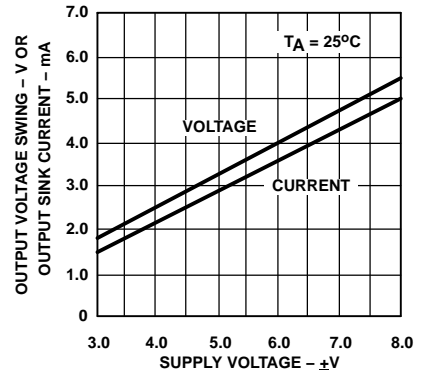


Figure 16. Output Voltage and Current Swing as a Function of Supply Voltage

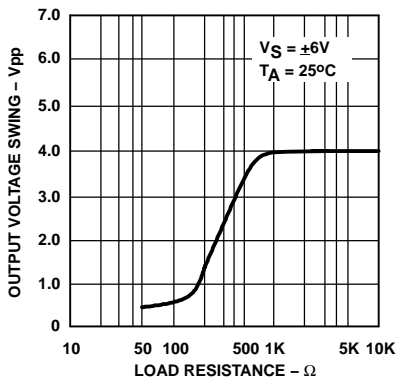


Figure 17. Output Voltage Swing as a Function of Load Resistance

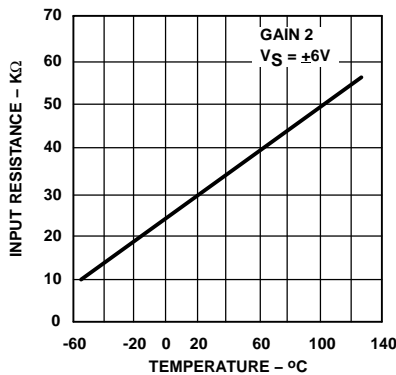


Figure 18. Input Resistance as a Function of Temperature

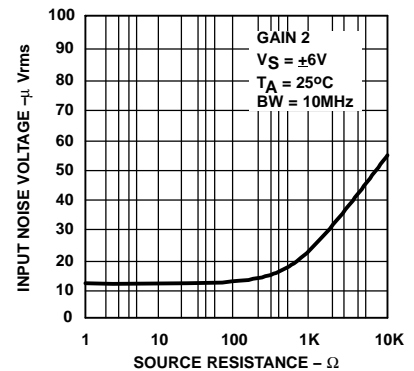


Figure 19. Input Noise Voltage as a Function of Source Resistance

TYPICAL PERFORMANCE CHARACTERISTICS

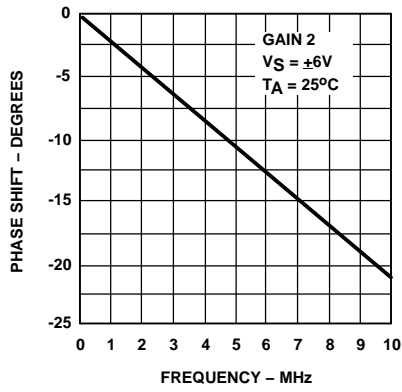


Figure 20. Phase Shift as a Function of Frequency

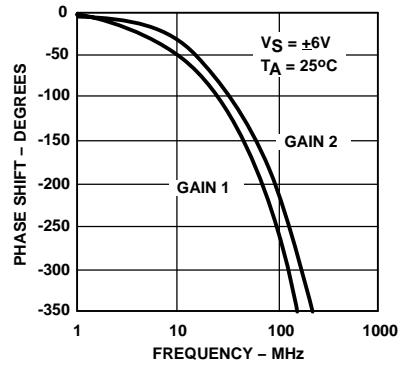


Figure 21. Phase Shift as a Function of Frequency

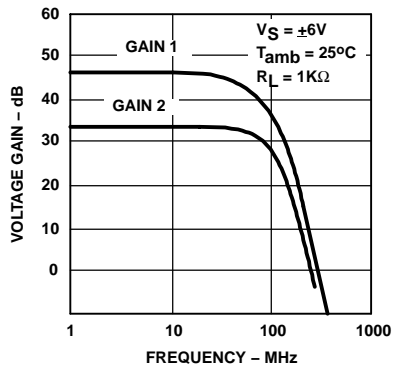


Figure 22. Voltage Gain as a Function of Frequency

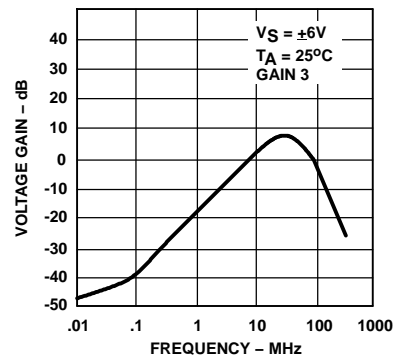


Figure 23. Voltage Gain as a Function of Frequency

TEST CIRCUITS ( $T_A = 25^\circ\text{C}$ , unless otherwise noted.)

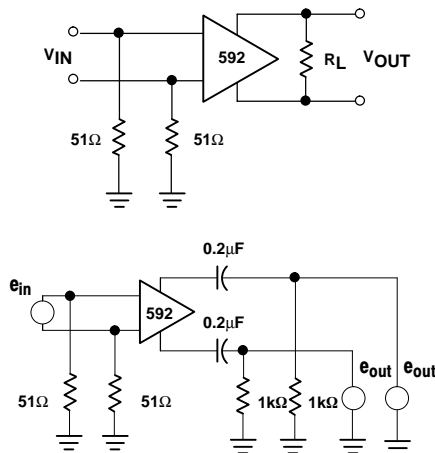


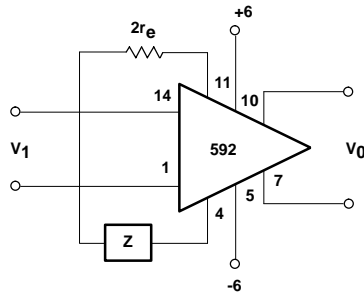
Figure 24. Test Circuits

# NE592

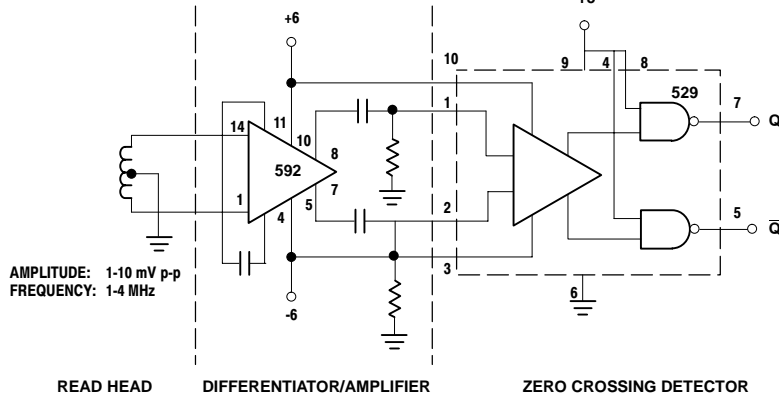
NOTE:

$$\frac{V_0(s)}{V_1(s)} \approx \frac{1.4 \cdot 10^4}{Z(s) + 2r_e}$$

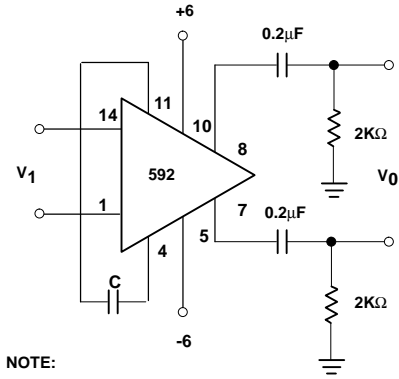
$$\approx \frac{1.4 \cdot 10^4}{Z(s) + 32}$$



Basic Configuration



Disc/Tape Phase-Modulated Readback Systems



NOTE:

For frequency  $F_1 \ll 1/2 \pi (32) C$

$$V_0 \approx 1.4 \times 10^4 C \frac{dV_i}{dt}$$

Differentiation with High Common-Mode Noise Rejection

Figure 25. Typical Applications

Z NETWORK	FILTER TYPE	$V_0(s)$ TRANSFER $V_1(s)$ FUNCTION
	LOW PASS	$\frac{1.4 \times 10^4}{L} \left[ \frac{1}{s + R/L} \right]$
	HIGH PASS	$\frac{1.4 \times 10^4}{R} \left[ \frac{s}{s + 1/RC} \right]$
	BAND PASS	$\frac{1.4 \times 10^4}{L} \left[ \frac{s}{s^2 + R/Ls + 1/LC} \right]$
	BAND REJECT	$\frac{1.4 \times 10^4}{R} \left[ \frac{s^2 + 1/LC}{s^2 + 1/LC + s/RC} \right]$

NOTES:

In the networks above, the R value used is assumed to include 2r<sub>e</sub>, or approximately 32Ω.

S = jω

ω = 2πf

Figure 26. Filter Networks



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## ORDERING INFORMATION

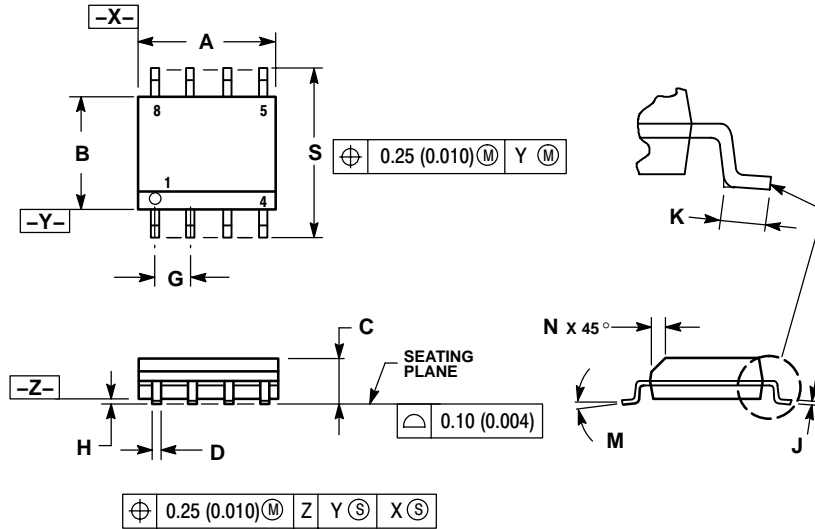
Device	Description	Temperature Range	Shipping†
NE592D8	8-Pin Small Outline Package	0 to +70°C	98 Units/Rail
NE592D8R2	8-Pin Small Outline Package	0 to +70°C	2500 Tape & Reel
NE592N8	8-Pin Plastic Dual In-Line Package	0 to +70°C	50 Units/Rail
NE592D14	14-Pin Small Outline Package	0 to +70°C	55 Units/Rail
NE592D14R2	14-Pin Small Outline Package	0 to +70°C	2500 Tape & Reel
NE592N14	14-Pin Plastic Dual In-Line Package	0 to +70°C	25 Units/Rail

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

# NE592

## PACKAGE DIMENSIONS

SOIC-8 NB  
D SUFFIX  
CASE 751-07  
ISSUE AC

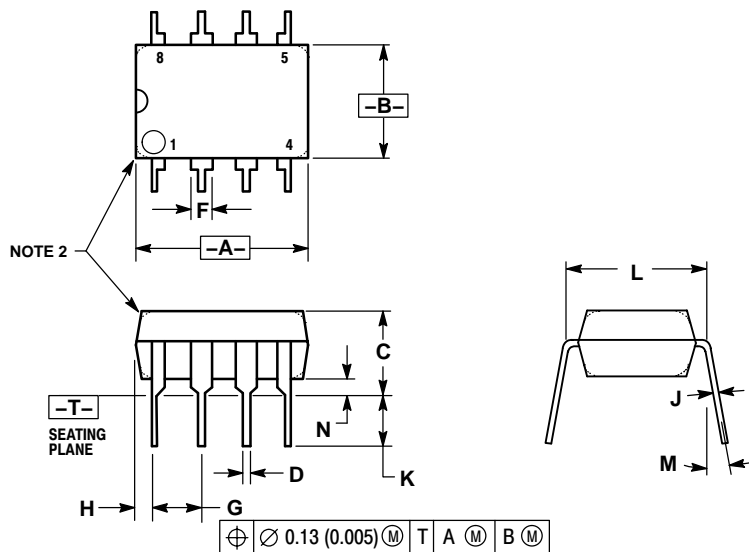


NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.80	5.00	0.189	0.197
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.053	0.069
D	0.33	0.51	0.013	0.020
G	1.27 BSC		0.050 BSC	
H	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
K	0.40	1.27	0.016	0.050
M	0°	8°	0°	8°
N	0.25	0.50	0.010	0.020
S	5.80	6.20	0.228	0.244

PDIP-8  
N SUFFIX  
CASE 626-05  
ISSUE L



NOTES:

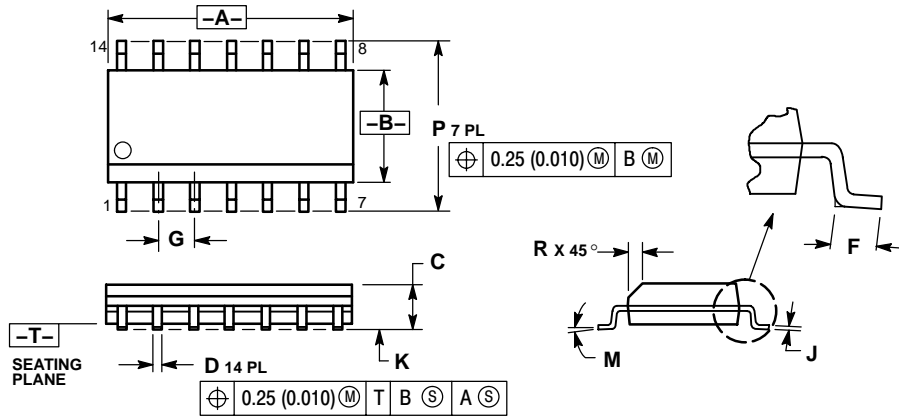
1. DIMENSION L TO CENTER OF LEAD WHEN FORMED PARALLEL.
2. PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
3. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	9.40	10.16	0.370	0.400
B	6.10	6.60	0.240	0.260
C	3.94	4.45	0.155	0.175
D	0.38	0.51	0.015	0.020
F	1.02	1.78	0.040	0.070
G	2.54 BSC		0.100 BSC	
H	0.76	1.27	0.030	0.050
J	0.20	0.30	0.008	0.012
K	2.92	3.43	0.115	0.135
L	7.62 BSC		0.300 BSC	
M	---	10°	---	10°
N	0.76	1.01	0.030	0.040

# NE592

## PACKAGE DIMENSIONS

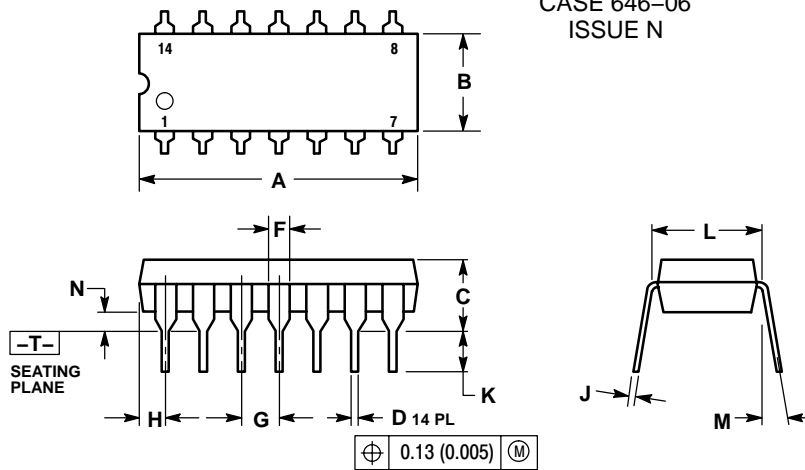
### SOIC-14 D SUFFIX CASE 751A-03 ISSUE G



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: MILLIMETER.
  3. DIMENSIONS A AND B DO NOT INCLUDE MOLD PROTRUSION.
  4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
  5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.


DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	8.55	8.75	0.337	0.344
B	3.80	4.00	0.150	0.157
C	1.35	1.75	0.054	0.068
D	0.35	0.49	0.014	0.019
F	0.40	1.25	0.016	0.049
G	1.27 BSC		0.050 BSC	
J	0.19	0.25	0.008	0.009
K	0.10	0.25	0.004	0.009
M	0°	7°	0°	7°
P	5.80	6.20	0.228	0.244
R	0.25	0.50	0.010	0.019

### PDIP-14 N SUFFIX CASE 646-06 ISSUE N



- NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
  2. CONTROLLING DIMENSION: INCH.
  3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL.
  4. DIMENSION B DOES NOT INCLUDE MOLD FLASH.
  5. ROUNDED CORNERS OPTIONAL.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.715	0.770	18.16	18.80
B	0.240	0.260	6.10	6.60
C	0.145	0.185	3.69	4.69
D	0.015	0.021	0.38	0.53
F	0.040	0.070	1.02	1.78
G	0.100 BSC		2.54 BSC	
H	0.052	0.095	1.32	2.41
J	0.008	0.015	0.20	0.38
K	0.115	0.135	2.92	3.43
L	0.290	0.310	7.37	7.87
M	---	10°	---	10°
N	0.015	0.039	0.38	1.01

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